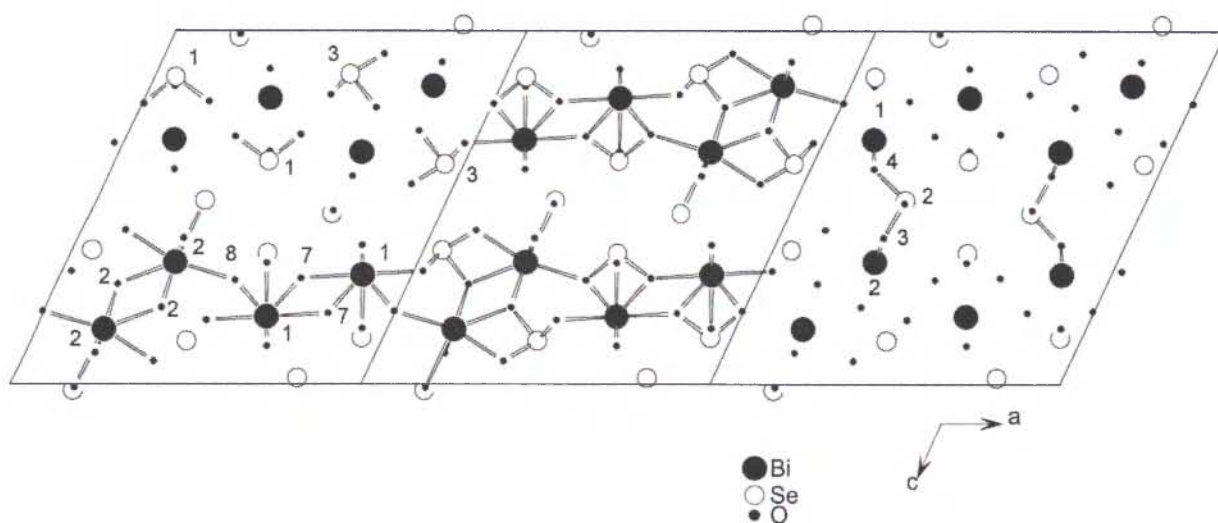


Crystal structure of bismuth selenite, $\text{Bi}_2(\text{SeO}_3)_3$

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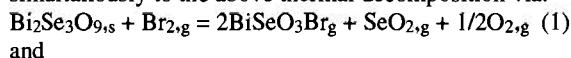


Abstract

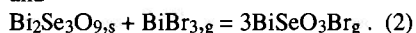
$\text{Bi}_2\text{O}_9\text{Se}_3$, monoclinic, $P12_1/n1$ (No. 14), $a = 13.491(1) \text{ \AA}$, $b = 4.675 \text{ \AA}$, $c = 14.961(1) \text{ \AA}$, $\beta = 115.164(4)^\circ$, $V = 854.1 \text{ \AA}^3$, $Z = 4$, $R(F) = 0.039$, $wR_{\text{ref}}(F^2) = 0.095$, $T = 293 \text{ K}$.

Source of material

The title compound is one of six at room temperature thermodynamically stable phases on the quasibinary line $\text{Bi}_2\text{O}_3\text{--SeO}_2$. The thermal decomposition gives solid Bi_2SeO_5 and gaseous SeO_2 in the measureable region from 623 K to 773 K [1]. $\text{Bi}_2\text{Se}_3\text{O}_9$ decomposes peritectical in solid Bi_2SeO_5 and SeO_2 -rich melt at $853 \text{ K} \pm 5 \text{ K}$. The decomposition pressure arises at this point 3 atm. $\text{Bi}_2\text{Se}_3\text{O}_9$ coexist in the O-poorer region with $\text{Bi}_2\text{SeO}_{5,s} + \text{Se}_1$ at the one side and $\text{Bi}_2\text{Se}_4\text{O}_{11,s}$ and Se_1 on the other side [2–4]. Phase pure $\text{Bi}_2\text{Se}_3\text{O}_9$ were obtained by sintering of stoichiometric mixtures of Bi_2O_3 and SeO_2 at 623 K. Single crystals are prepared by chemical transport reaction with BiBr_3 or Br_2 . Phase pure $\text{Bi}_2\text{Se}_3\text{O}_9$ was closed in evacuated quartz tubes with some mg BiBr_3 or Br_2 and transported in a temperature gradient from 773 K to 673 K. The transport rate in ampoules of 15 cm length and 1.5 cm diameter arises 0.1 mg/h. The crystals are clear prisms of 1–2 mm length. We understud the transport simultaneously to the above thermal decomposition via:



and



For the existence of gaseous BiSeO_3Br see [5].

Discussion

The structure of $\text{Bi}_2\text{Se}_3\text{O}_9$ include two distorted, slightly different octahedra $[\text{Bi}(1)\text{O}_6]^{9-}$ and $[\text{Bi}(2)\text{O}_6]^{9-}$ (bond lengths 2.247 Å to 2.516 Å and 2.257 Å to 2.563 Å, respectively) as well as the trigonal-pyramidal units $[\text{Se}(1)\text{O}_3]^{2-}$, $[\text{Se}(2)\text{O}_3]^{2-}$ and $[\text{Se}(3)\text{O}_3]^{2-}$. Oxygen atoms linked by edgesthe $[\text{Bi}(1)\text{O}_6]^{9-}$ polyhedra (O(7)) and the $[\text{Bi}(2)\text{O}_6]^{9-}$ polyhedra (O(2)) to chains along b -axis direction. Both chains are corner-linked over O(8) in direction of a -axis and form Bi–O double layers $[\text{Bi}_2\text{O}_9]^{12-}$ along the a – b plane (see figure, left part, down). These layers include the both polyhedra $[\text{Se}(1)\text{O}_3]^{2-}$ and $[\text{Se}(3)\text{O}_3]^{2-}$ (figure, left part, up) and generated the $[\text{Bi}_2\text{Se}_2\text{O}_9]^{4-}$ layers as the characteristical layer unit of the $\text{Bi}_2(\text{SeO}_3)_3$ structure (see figure, middle part). Between these $[\text{Bi}_2\text{Se}_2\text{O}_9]^{4-}$ layers enclosed a weak $[\text{Se}(2)\text{O}_3]^{2-}$ layer, bonded to the main layers over Bi(1)–O(4)–Se(2)–O(3)–Bi(2) (right part in the figure).

Table 1. Data collection and handling.

Crystal:	colourless, clear prism, size $0.04 \times 0.07 \times 0.25 \text{ mm}$
Wavelength:	Mo K_α radiation ($0.71073 \text{ \AA}$)
μ :	521.81 cm^{-1}
Diffractometer, scan mode:	Enraf-Nonius CAD4, $\omega/2\theta$
$2\theta_{\text{max}}$:	55.98°
$N(hkl)_{\text{measured}}$, $N(hkl)_{\text{unique}}$:	4266, 2057
Criterion for I_{obs} , $N(hkl)_{\text{gt}}$:	$I_{\text{obs}} > 2 \sigma(I_{\text{obs}})$, 1763
$N(\text{param})_{\text{refined}}$:	128
Programs:	SHELXS-97 [6], SHELXL-97 [7], DIAMOND [8]

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Table 2. Atomic coordinates and displacement parameters (in Å²).

Atom	Site	x	y	z	U ₁₁	U ₂₂	U ₃₃	U ₁₂	U ₁₃	U ₂₃
Bi(1)	4e	0.64092(3)	0.13774(8)	0.80963(3)	0.0116(2)	0.0161(2)	0.0231(2)	0.0004(1)	0.0082(2)	0.0001(1)
Bi(2)	4e	0.80771(3)	0.13518(7)	0.15550(3)	0.0122(2)	0.0156(2)	0.0212(2)	0.0002(1)	0.0096(2)	0.0003(1)
Se(1)	4e	0.93979(8)	0.0942(2)	0.86907(7)	0.0111(5)	0.0156(4)	0.0202(4)	0.0008(4)	0.0074(4)	0.0003(3)
Se(2)	4e	0.68934(8)	0.1173(2)	0.51830(7)	0.0127(5)	0.0159(5)	0.0207(4)	0.0012(4)	0.0085(4)	0.0001(3)
Se(3)	4e	0.55426(8)	0.2142(2)	0.12201(7)	0.0107(5)	0.0199(5)	0.0246(5)	0.0003(4)	0.0101(4)	0.0002(4)
O(1)	4e	0.4295(7)	0.052(2)	0.3426(5)	0.021(4)	0.019(3)	0.026(3)	−0.002(3)	0.008(3)	−0.002(3)
O(2)	4e	0.1728(6)	0.153(2)	0.7170(5)	0.013(4)	0.027(4)	0.025(3)	0.003(3)	0.010(3)	0.006(3)
O(3)	4e	0.6991(7)	0.197(2)	0.4119(5)	0.024(4)	0.021(4)	0.027(3)	0.000(3)	0.012(3)	0.002(3)
O(4)	4e	0.8188(6)	0.169(2)	0.6072(6)	0.013(4)	0.023(4)	0.030(4)	0.001(3)	0.004(3)	0.000(3)
O(5)	4e	0.4739(7)	0.059(2)	0.8193(6)	0.026(4)	0.029(4)	0.032(4)	0.000(4)	0.019(3)	0.004(3)
O(6)	4e	0.6232(6)	0.051(2)	0.0652(5)	0.014(4)	0.040(4)	0.023(3)	−0.007(3)	0.012(3)	−0.012(3)
O(7)	4e	0.1883(6)	0.035(2)	0.2001(5)	0.010(3)	0.018(3)	0.028(3)	0.002(3)	0.011(3)	−0.002(3)
O(8)	4e	0.0041(6)	0.031(2)	0.2064(5)	0.010(3)	0.026(4)	0.031(3)	0.001(3)	0.011(3)	−0.004(3)
O(9)	4e	0.3110(6)	0.246(2)	0.4903(5)	0.023(4)	0.016(3)	0.022(3)	0.000(3)	0.009(3)	0.003(3)

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